Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	333626	poly or polysilicon or "poly Si" or "poly-Si" or "poly silicon" or "poly-silicon" or "polycrystalline Si" or "polycrystalline-Si" or "polycrystalline silicon" or "polycrystalline-silicon"	US-PGPUB; USPAT	OR	ON	2005/05/20 11:15
L2	1988	(poly or polysilicon or "poly Si" or "poly-Si" or "poly silicon" or "poly-silicon" or "polycrystalline Si" or "polycrystalline-Si" or "polycrystalline silicon" or "polycrystalline-silicon") with (conformal or "same shape" or "same-shape")	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L3	54104	mandrel	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L4	5	2 with 3	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L5	4116912	@ad<"20030626"	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L6	4	4 and 5	US-PGPUB; USPAT	OR	ON	2005/05/20 12:18
L7	1535455	heat or heats or heated or heating or anneal\$	US-PGPUB; USPAT	OR	ON	2005/05/20 12:17
L8	0	6 and 7	US-PGPUB; USPAT	OR	ON	2005/05/20 12:17
L9	671293	crystal\$	US-PGPUB; USPAT	OR	ON	2005/05/20 12:18
L10	3	6 and 9	US-PGPUB; USPAT	OR	ON	2005/05/20 12:19
L11	2265081	T or temperature or Celsius or Farenheit	US-PGPUB; USPAT	OR	ON	2005/05/20 12:20
L12	2	6 and 11	US-PGPUB; USPAT	OR	ON	2005/05/20 12:20

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	333626	poly or polysilicon or "poly Si" or "poly-Si" or "poly silicon" or "poly-silicon" or "polycrystalline Si" or "polycrystalline-Si" or "polycrystalline silicon" or "polycrystalline-silicon"	US-PGPUB; USPAT	OR	ON	2005/05/20 11:15
1.2	1988	(poly or polysilicon or "poly Si" or "poly-Si" or "poly silicon" or "poly-silicon" or "polycrystalline Si" or "polycrystalline-Si" or "polycrystalline silicon" or "polycrystalline-silicon") with (conformal or "same shape" or "same-shape")	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L3	54104	mandrel	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L4	5	2 with 3	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L5	4116912	@ad<"20030626"	US-PGPUB; USPAT	OR	ON	2005/05/20 11:37
L6	4	4 and 5	US-PGPUB; USPAT	OR	ON	2005/05/20 12:18
L7	1535455	heat or heats or heated or heating or anneal\$	US-PGPUB; USPAT	OR	ON	2005/05/20 12:17
L8	0	6 and 7	US-PGPUB; USPAT	OR	ON	2005/05/20 12:17
L9	671293	crystal\$	US-PGPUB; USPAT	OR	ON	2005/05/20 12:18
L10	3	6 and 9	US-PGPUB; USPAT	OR	ON	2005/05/20 12:19
L11	2265081	T or temperature or Celsius or Farenheit	US-PGPUB; USPAT	OR	ON	2005/05/20 12:20
L12	2	6 and 11	US-PGPUB; USPAT	OR	ON	2005/05/20 12:37
L13	6937	"2212"	US-PGPUB; USPAT	OR	ON	2005/05/20 12:38
L14	1	"20020181523"	US-PGPUB; USPAT	OR	ON	2005/05/20 12:39
L15	2	(("5723370") or ("6492212")).PN.	US-PGPUB; USPAT	OR	OFF	2005/05/20 12:39
L16	3	14 or 15	US-PGPUB; USPAT	OR	ON	2005/05/20 12:46
L17	797382	gate or electrode	US-PGPUB; USPAT	OR	ON	2005/05/20 12:46

L18	3	16 and 17	US-PGPUB; USPAT	OR	ON	2005/05/20 12:47
L19	3	6 and 17	US-PGPUB; USPAT	OR	ON	2005/05/20 13:49
L20	555489	grow\$	US-PGPUB; USPAT	OR	ON	2005/05/20 13:49
L21	3	6 and 17	US-PGPUB; USPAT	OR	ON	2005/05/20 13:52
L22	1	("5328810").PN.	US-PGPUB; USPAT	OR	OFF	2005/05/20 13:52
L23	0	("grow\$").PN.	US-PGPUB; USPAT	OR	OFF	2005/05/20 13:52
L24	1	("20050009305").PN.	US-PGPUB; USPAT	OR	OFF	2005/05/20 13:53
L25	555489	grow\$	US-PGPUB; USPAT	OR	ON	2005/05/20 13:53
L26	1	22 and 25	US-PGPUB; USPAT	OR	ON	2005/05/20 14:04
L27	138868	anneal\$	US-PGPUB; USPAT	OR	ON	2005/05/20 14:04
L28	0	22 and 27	US-PGPUB; USPAT	OR	ON	2005/05/20 14:53
L29	17696	SOI	US-PGPUB; USPAT	OR	ON	2005/05/20 14:53
L30	0	22 and 29	US-PGPUB; USPAT	OR	ON	2005/05/20 15:23
L31	5001	((438/166) or (438/482) or (438/485) or (438/486) or (438/496) or (438/606) or (438/631) or (438/636) or (438/660) or (438/778)).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/05/20 15:25
L32	43	2 and 31	US-PGPUB; USPAT	OR	ON	2005/05/20 15:25
L33	42	5 and 32	US-PGPUB; USPAT	OR	ON	2005/05/20 15:25